

# LDO Regulator, 100 mA, 18 V, 1 $\mu$ A $I_Q$ , with PG NCV8711

The NCV8711 device is based on unique combination of features – very low quiescent current, fast transient response and high input and output voltage ranges. The NCV8711 is CMOS LDO regulator designed for up to 18 V input voltage and 100 mA output current. Quiescent current of only 1  $\mu$ A makes this device ideal solution for battery-powered, always-on systems. Several fixed output voltage versions are available as well as the adjustable version.

The device (version B) implements power good circuit (PG) which indicates that output voltage is in regulation. This signal could be used for power sequencing or as a microcontroller reset.

Internal short circuit and over temperature protections saves the device against overload conditions.

## Features

- Operating Input Voltage Range: 2.7 V to 18 V
- Output Voltage: 1.2 V to 17 V
- Capable of Sourcing 140 mA Peak Output Current
- Very Low Quiescent Current: 1  $\mu$ A typ.
- Low Dropout: 215 mV typ. at 100 mA
- Output Voltage Accuracy  $\pm 1\%$
- Power Good Output (Version B)
- Stable with Small 1  $\mu$ F Ceramic Capacitors
- Built-in Soft Start Circuit to Suppress Inrush Current
- Over-Current and Thermal Shutdown Protections
- Available in Small TSOP-5 and WDFNW6 (2x2) Packages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

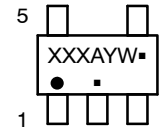
## Typical Applications

- Body Control Modules
- LED Lighting
- On Board Charger
- General Purpose Automotive

## MARKING DIAGRAMS

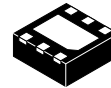


TSOP-5  
CASE 483  
SN SUFFIX

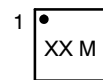


XXX = Specific Device Code  
A = Assembly Location  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

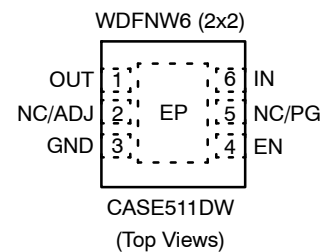
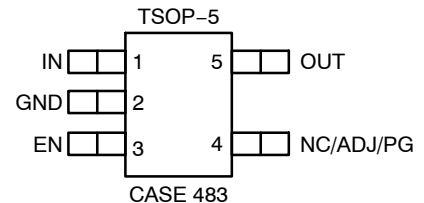


WDFNW6 (2x2)  
CASE 511DW  
MTW SUFFIX



XX = Specific Device Code  
M = Date Code

## PIN ASSIGNMENTS



## ORDERING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet.

# NCV8711

## TYPICAL APPLICATION SCHEMATICS

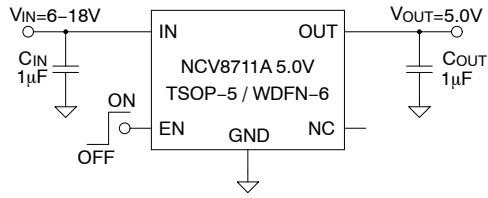


Figure 1. Fixed Output Voltage Application (No PG)

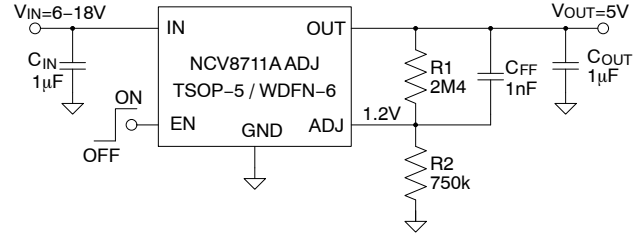


Figure 2. Adjustable Output Voltage Application (No PG)

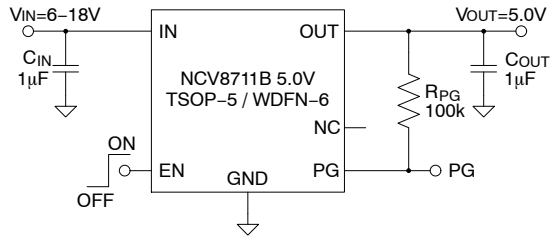


Figure 3. Fixed Output Voltage Application with PG

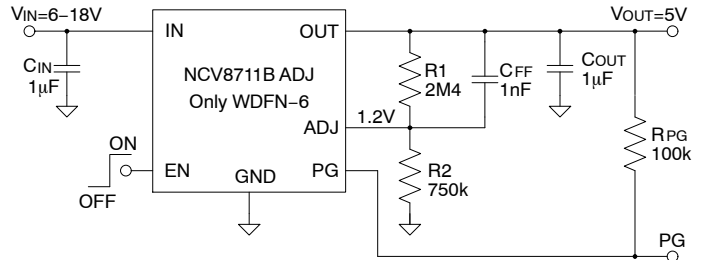
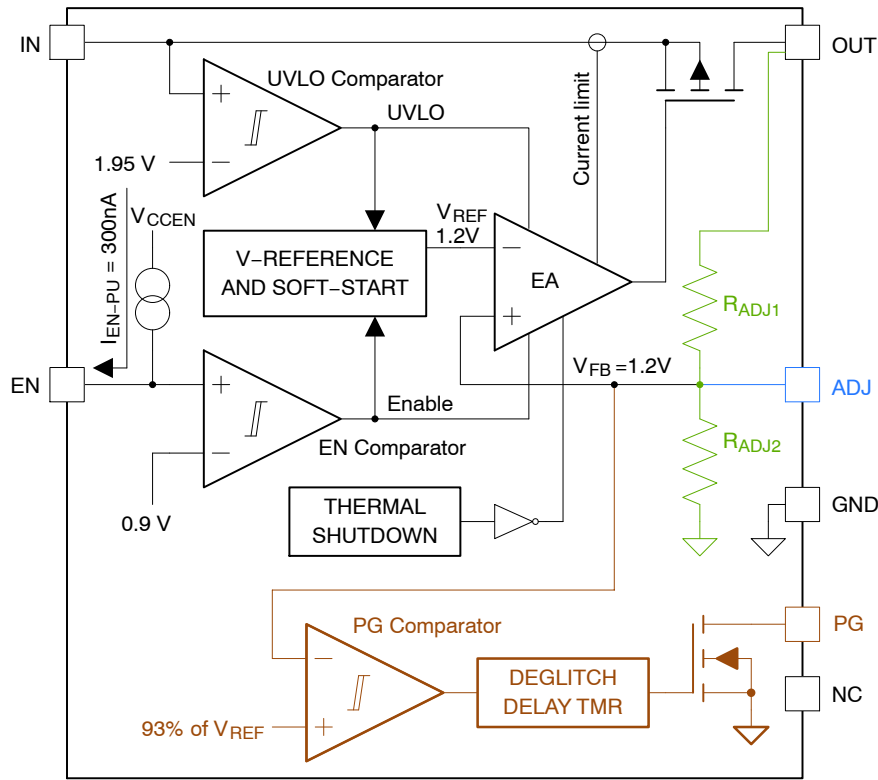


Figure 4. Adjustable Output Voltage Application with PG

$$V_{OUT} = V_{ADJ} \cdot \left(1 + \frac{R_1}{R_2}\right) + I_{ADJ} \cdot R_1$$

SIMPLIFIED BLOCK DIAGRAMS



Note: Blue objects are valid for ADJ version  
 Green objects are valid for FIX version  
 Brown objects are valid for B version (with PG)

Figure 5. Internal Block Diagram

PIN DESCRIPTION

| Pin No. TSOP-5 | Pin No. WDFNW6 | Pin Name | Description                                                                                                                                                                  |
|----------------|----------------|----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1              | 6              | IN       | Power supply input pin.                                                                                                                                                      |
| 2              | 3              | GND      | Ground pin.                                                                                                                                                                  |
| 5              | 1              | OUT      | LDO output pin.                                                                                                                                                              |
| 3              | 4              | EN       | Enable input pin (high – enabled, low – disabled). If this pin is connected to IN pin or if it is left unconnected (pull-up resistor is not required) the device is enabled. |
| 4 (Note 1)     | 2              | ADJ      | Adjust input pin. Connect it to the output resistor divider or directly to the OUT pin.                                                                                      |
| 4 (Note 1)     | 5              | PG       | Power good output pin. Could be left unconnected or could be connected to GND if not needed. High level for power ok, low level for fail.                                    |
| 4 (Note 1)     | 2, 5           | NC       | Not internally connected. This pin can be tied to the ground plane to improve thermal dissipation.                                                                           |
| NA             | EP             | EPAD     | Connect the exposed pad to GND.                                                                                                                                              |

1. Pin function depends on device version.

## MAXIMUM RATINGS

| Rating                                        | Symbol              | Value                                                                                                                                                                                                                                 | Unit |
|-----------------------------------------------|---------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| VIN Voltage (Note 2)                          | V <sub>IN</sub>     | –0.3 to 22                                                                                                                                                                                                                            | V    |
| VOU Voltage                                   | V <sub>OUT</sub>    | ADJ version & FIX versions V <sub>OUT-NOM</sub> > 5.0 V:<br>–0.3 to [(V <sub>IN</sub> + 0.3) or 22; whichever is lower]<br>FIX versions V <sub>OUT-NOM</sub> ≤ 5.0 V:<br>–0.3 to [(V <sub>IN</sub> + 0.3) or 6.0; whichever is lower] | V    |
| EN Voltage                                    | V <sub>EN</sub>     | –0.3 to (V <sub>IN</sub> + 0.3)                                                                                                                                                                                                       | V    |
| ADJ Voltage                                   | V <sub>FB/ADJ</sub> | –0.3 to 5.5                                                                                                                                                                                                                           | V    |
| PG Voltage                                    | V <sub>PG</sub>     | –0.3 to (V <sub>IN</sub> + 0.3)                                                                                                                                                                                                       | V    |
| Output Current                                | I <sub>OUT</sub>    | Internally limited                                                                                                                                                                                                                    | mA   |
| PG Current                                    | I <sub>PG</sub>     | 3                                                                                                                                                                                                                                     | mA   |
| Maximum Junction Temperature                  | T <sub>J(MAX)</sub> | 150                                                                                                                                                                                                                                   | °C   |
| Storage Temperature                           | T <sub>STG</sub>    | –55 to 150                                                                                                                                                                                                                            | °C   |
| ESD Capability, Human Body Model (Note 3)     | ESD <sub>HBM</sub>  | 2000                                                                                                                                                                                                                                  | V    |
| ESD Capability, Charged Device Model (Note 3) | ESD <sub>CDM</sub>  | 1000                                                                                                                                                                                                                                  | V    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

3. This device series incorporates ESD protection and is tested by the following methods:

ESD Human Body Model tested per ANSI/ESDA/JEDEC JS–001, EIA/JESD22–A114 (AEC–Q100–002)

ESD Charged Device Model tested per ANSI/ESDA/JEDEC JS–002, EIA/JESD22–C101 (AEC–Q100–011D)

## THERMAL CHARACTERISTICS (Note 4)

| Characteristic                                              | Symbol             | WDFNW6 2x2 | TSOP–5 | Unit |
|-------------------------------------------------------------|--------------------|------------|--------|------|
| Thermal Resistance, Junction–to–Air                         | R <sub>thJA</sub>  | 67         | 178    | °C/W |
| Thermal Resistance, Junction–to–Case (top)                  | R <sub>thJCt</sub> | 89         | 93     | °C/W |
| Thermal Resistance, Junction–to–Case (bottom)               | R <sub>thJCb</sub> | 11         | N/A    | °C/W |
| Thermal Resistance, Junction–to–Board (top)                 | R <sub>thJBt</sub> | 44         | 53     | °C/W |
| Thermal Characterization Parameter, Junction–to–Case (top)  | Ψ <sub>siJCt</sub> | 4.6        | 18     | °C/W |
| Thermal Characterization Parameter, Junction–to–Board [FEM] | Ψ <sub>siJB</sub>  | 44         | 53     | °C/W |

4. Measured according to JEDEC board specification (board 1S2P, Cu layer thickness 1 oz, Cu area 650 mm<sup>2</sup>, no airflow). Detailed description of the board can be found in JESD51–7.

**ELECTRICAL CHARACTERISTICS** (V<sub>IN</sub> = V<sub>OUT-NOM</sub> + 1 V and V<sub>IN</sub> ≥ 2.7 V, V<sub>EN</sub> = 1.2 V, I<sub>OUT</sub> = 1 mA, C<sub>IN</sub> = C<sub>OUT</sub> = 1.0 μF (effective capacitance – Note 5), T<sub>J</sub> = –40°C to 125°C, ADJ tied to OUT, unless otherwise specified) (Note 6)

| Parameter                     | Test Conditions                                                                  | Symbol               | Min  | Typ  | Max | Unit              |
|-------------------------------|----------------------------------------------------------------------------------|----------------------|------|------|-----|-------------------|
| Recommended Input Voltage     |                                                                                  | V <sub>IN</sub>      | 2.7  | –    | 18  | V                 |
| Output Voltage Accuracy       | T <sub>J</sub> = –40°C to +85°C                                                  | V <sub>OUT</sub>     | –1   | –    | 1   | %                 |
|                               | T <sub>J</sub> = –40°C to +125°C                                                 |                      | –1   | –    | 2   |                   |
| ADJ Reference Voltage         | ADJ version only                                                                 | V <sub>ADJ</sub>     | –    | 1.2  | –   | V                 |
| ADJ Input Current             | V <sub>ADJ</sub> = 1.2 V                                                         | I <sub>ADJ</sub>     | –0.1 | 0.01 | 0.1 | μA                |
| Line Regulation               | V <sub>IN</sub> = V <sub>OUT-NOM</sub> + 1 V to 18 V and V <sub>IN</sub> ≥ 2.7 V | ΔV <sub>O(ΔVI)</sub> | –    | –    | 0.2 | %V <sub>OUT</sub> |
| Load Regulation               | I <sub>OUT</sub> = 0.1 mA to 100 mA                                              | ΔV <sub>O(ΔIO)</sub> | –    | –    | 0.4 | %V <sub>OUT</sub> |
| Quiescent Current (version A) | V <sub>IN</sub> = V <sub>OUT-NOM</sub> + 1 V to 18 V, I <sub>OUT</sub> = 0 mA    | I <sub>Q</sub>       | –    | 1.3  | 2.5 | μA                |
| Quiescent Current (version B) | V <sub>IN</sub> = V <sub>OUT-NOM</sub> + 1 V to 18 V, I <sub>OUT</sub> = 0 mA    |                      | –    | 1.8  | 3.0 |                   |
| Ground Current                | I <sub>OUT</sub> = 100 mA                                                        | I <sub>GND</sub>     | –    | 325  | 450 | μA                |
| Shutdown Current (Note 10)    | V <sub>EN</sub> = 0 V, I <sub>OUT</sub> = 0 mA, V <sub>IN</sub> = 18 V           | I <sub>SHDN</sub>    | –    | 0.35 | 1.5 | μA                |
| Output Current Limit          | V <sub>OUT</sub> = V <sub>OUT-NOM</sub> – 100 mV                                 | I <sub>OLIM</sub>    | 140  | 250  | 450 | mA                |
| Short Circuit Current         | V <sub>OUT</sub> = 0 V                                                           | I <sub>OSC</sub>     | 140  | 250  | 450 | mA                |

**ELECTRICAL CHARACTERISTICS** ( $V_{IN} = V_{OUT-NOM} + 1\text{ V}$  and  $V_{IN} \geq 2.7\text{ V}$ ,  $V_{EN} = 1.2\text{ V}$ ,  $I_{OUT} = 1\text{ mA}$ ,  $C_{IN} = C_{OUT} = 1.0\text{ }\mu\text{F}$  (effective capacitance – Note 5),  $T_J = -40^\circ\text{C}$  to  $125^\circ\text{C}$ , ADJ tied to OUT, unless otherwise specified) (Note 6) (continued)

| Parameter                            | Test Conditions                                                          |         | Symbol              | Min  | Typ  | Max  | Unit              |
|--------------------------------------|--------------------------------------------------------------------------|---------|---------------------|------|------|------|-------------------|
| Dropout Voltage (Note 7)             | I <sub>OUT</sub> = 100 mA                                                |         | V <sub>DO</sub>     | –    | 215  | 355  | mV                |
| Power Supply Ripple Rejection        | V <sub>IN</sub> = V <sub>OUT-NOM</sub> + 2 V<br>I <sub>OUT</sub> = 10 mA | 10 Hz   | PSRR                | –    | 80   | –    | dB                |
|                                      |                                                                          | 10 kHz  |                     | –    | 70   | –    |                   |
|                                      |                                                                          | 100 kHz |                     | –    | 42   | –    |                   |
|                                      |                                                                          | 1 MHz   |                     | –    | 48   | –    |                   |
| Output Noise                         | f = 10 Hz to 100 kHz, V <sub>OUT-NOM</sub> = 5.0 V                       |         | V <sub>N</sub>      | –    | 240  | –    | μV <sub>RMS</sub> |
| EN Threshold                         | V <sub>EN</sub> rising                                                   |         | V <sub>EN-TH</sub>  | 0.7  | 0.9  | 1.05 | V                 |
| EN Hysteresis                        | V <sub>EN</sub> falling                                                  |         | V <sub>EN-HY</sub>  | 0.01 | 0.1  | 0.2  | V                 |
| EN Internal Pull-up Current          | V <sub>EN</sub> = 1 V, V <sub>IN</sub> = 5.5 V                           |         | I <sub>EN-PU</sub>  | 0.01 | 0.3  | 1    | μA                |
| EN Input Leakage Current             | V <sub>EN</sub> = 18 V, V <sub>IN</sub> = 18 V                           |         | I <sub>EN-LK</sub>  | –1   | 0.05 | 1    | μA                |
| Start-up time (Note 8)               | V <sub>OUT-NOM</sub> ≤ 3.3 V                                             |         | t <sub>START</sub>  | 100  | 250  | 500  | μs                |
|                                      | V <sub>OUT-NOM</sub> > 3.3 V                                             |         |                     | 300  | 600  | 1000 |                   |
| Internal UVLO Threshold              | Ramp V <sub>IN</sub> up until output is turned on                        |         | V <sub>IUL-TH</sub> | 1.6  | 1.95 | 2.6  | V                 |
| Internal UVLO Hysteresis             | Ramp V <sub>IN</sub> down until output is turned off                     |         | V <sub>IUL-HY</sub> | 0.05 | 0.2  | 0.3  | V                 |
| PG Threshold (Note 9)                | V <sub>OUT</sub> falling                                                 |         | V <sub>PG-TH</sub>  | 90   | 93   | 96   | %                 |
| PG Hysteresis (Note 9)               | V <sub>OUT</sub> rising                                                  |         | V <sub>PG-HY</sub>  | 0.1  | 2    | 4    | %                 |
| PG Deglitch Time (Note 9)            |                                                                          |         | t <sub>PG-DG</sub>  | 75   | 160  | 270  | μs                |
| PG Delay Time (Note 9)               |                                                                          |         | t <sub>PG-DLY</sub> | 120  | 320  | 600  | μs                |
| PG Output Low Level Voltage (Note 9) | I <sub>PG</sub> = 1 mA                                                   |         | V <sub>PG-OL</sub>  | –    | 0.2  | 0.4  | V                 |
| PG Output Leakage Current (Note 9)   | V <sub>PG</sub> = 18 V                                                   |         | I <sub>PG-LK</sub>  | –    | 0.01 | 1    | μA                |
| Thermal Shutdown Temperature         | Temperature rising from T <sub>J</sub> = +25°C                           |         | T <sub>SD</sub>     | –    | 165  | –    | °C                |
| Thermal Shutdown Hysteresis          | Temperature falling from T <sub>SD</sub>                                 |         | T <sub>SDH</sub>    | –    | 20   | –    | °C                |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Effective capacitance, including the effect of DC bias, tolerance and temperature. See the Application Information section for more information.
- Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at  $T_A = 25^\circ\text{C}$ . Low duty cycle pulse techniques are used during the testing to maintain the junction temperature as close to ambient as possible.
- Dropout measured when the output voltage falls 100 mV below the nominal output voltage. Limits are valid for all voltage versions with nominal output voltage higher than or equal to 2.5 V. For lower output voltage versions, the dropout test is not applied because the input voltage during the test would fall below the minimum input voltage 2.7 V.
- Startup time is the time from EN assertion to point when output voltage is equal to 95% of  $V_{OUT-NOM}$ .
- Applicable only to version B (device option with power good output). PG threshold and PG hysteresis are expressed in percentage of nominal output voltage.
- Shutdown current includes EN Internal Pull-up Current.

# TYPICAL CHARACTERISTICS

$V_{IN} = V_{OUT-NOM} + 1\text{ V}$  AND  $V_{IN} \geq 2.7\text{ V}$ ,  $V_{EN} = 1.2\text{ V}$ ,  $I_{OUT} = 1\text{ mA}$ ,  $C_{OUT} = 1.0\text{ MF}$ , ADJ TIED TO OUT,  $T_J = 25^\circ\text{C}$ , UNLESS OTHERWISE SPECIFIED

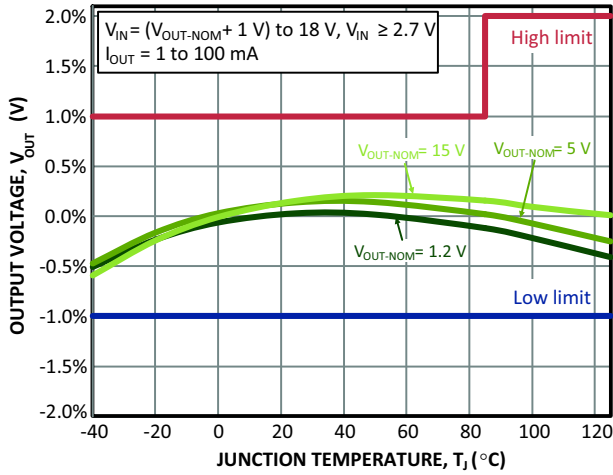


Figure 6. Output Voltage vs. Temperature

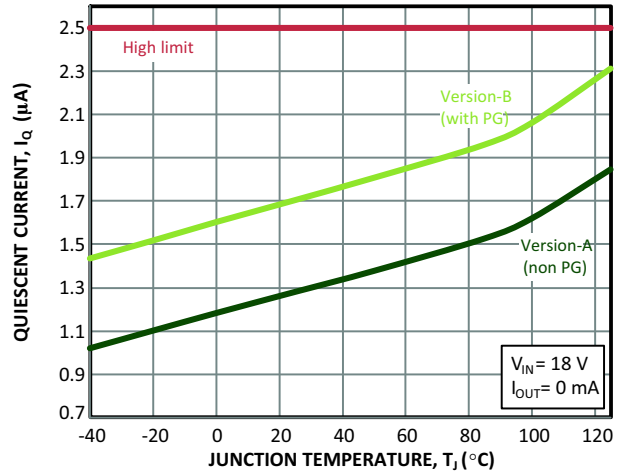


Figure 7. Quiescent Current vs. Temperature

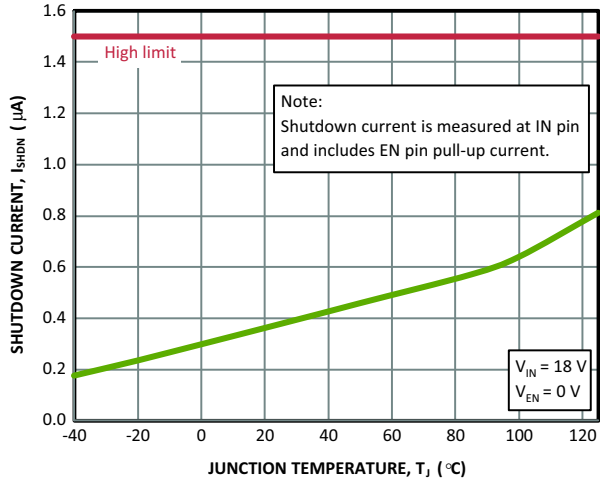


Figure 8. Shutdown Current vs. Temperature

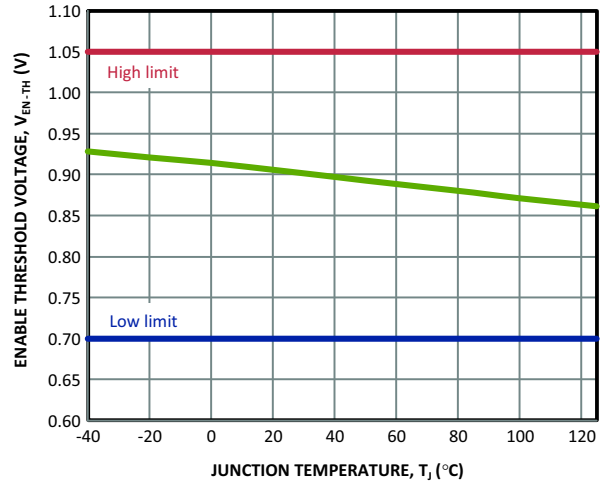


Figure 9. Enable Threshold Voltage vs. Temperature

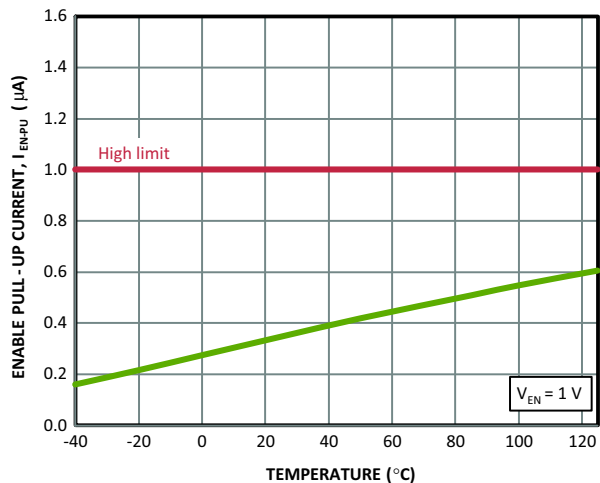


Figure 10. Enable Internal Pull-Up Current vs. Temperature

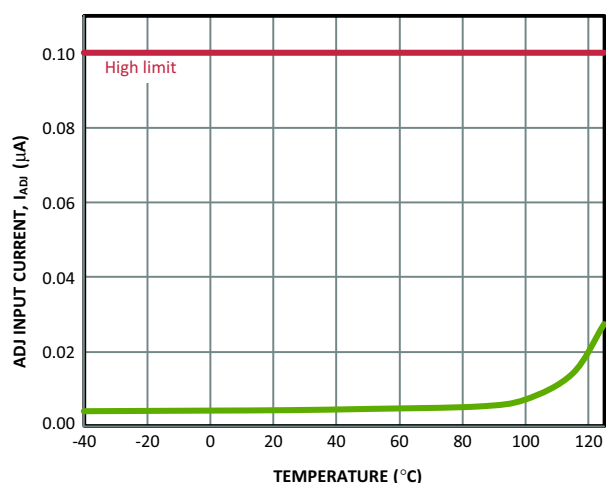
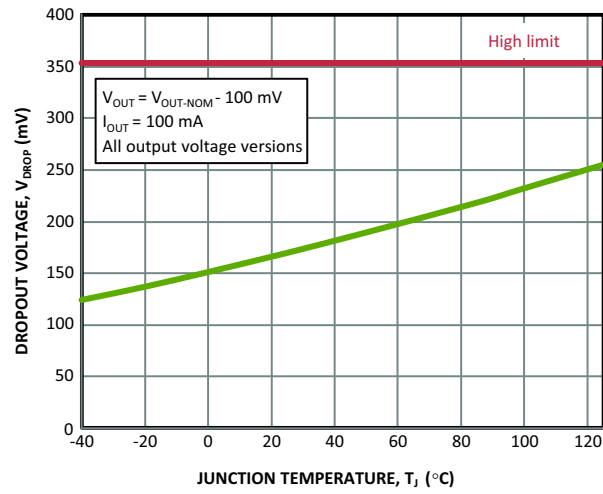


Figure 11. ADJ Input Current vs. Temperature

**TYPICAL CHARACTERISTICS**

$V_{IN} = V_{OUT-NOM} + 1\text{ V}$  AND  $V_{IN} \geq 2.7\text{ V}$ ,  $V_{EN} = 1.2\text{ V}$ ,  $I_{OUT} = 1\text{ mA}$ ,  $C_{OUT} = 1.0\text{ MF}$ , ADJ TIED TO OUT,  $T_J = 25^\circ\text{C}$ , UNLESS OTHERWISE SPECIFIED



**Figure 12. Dropout Voltage vs. Temperature**

# TYPICAL CHARACTERISTICS

$V_{IN} = V_{OUT-NOM} + 1\text{ V}$  AND  $V_{IN} \geq 2.7\text{ V}$ ,  $V_{EN} = 1.2\text{ V}$ ,  $I_{OUT} = 1\text{ mA}$ ,  $C_{OUT} = 1.0\text{ MF}$ , ADJ TIED TO OUT,  $T_J = 25^\circ\text{C}$ , UNLESS OTHERWISE SPECIFIED

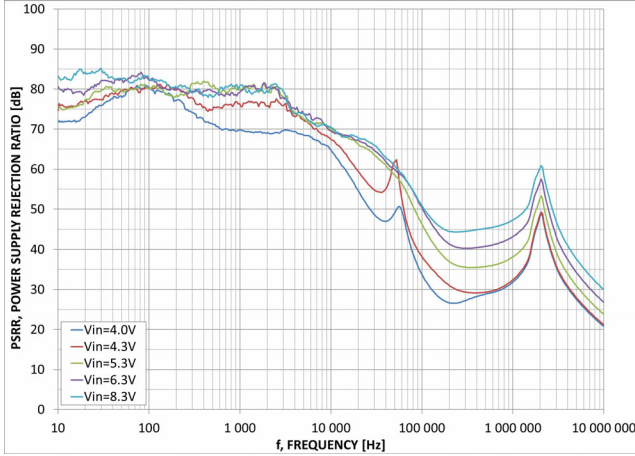


Figure 13. PSRR – FIX–3.3 V,  $C_{OUT} = 1\text{ }\mu\text{F}$ ,  $I_{OUT} = 100\text{ mA}$

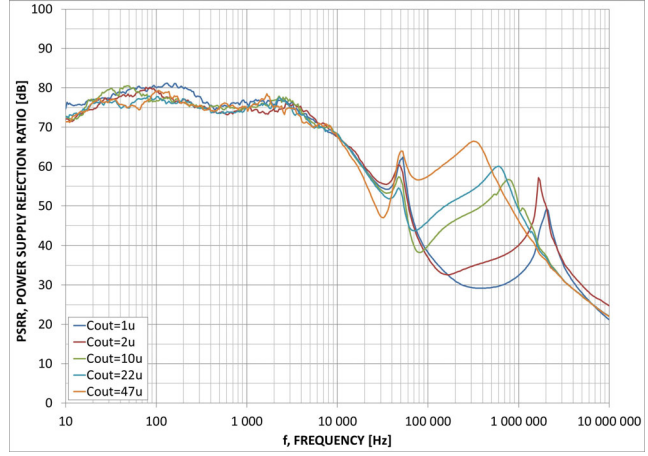


Figure 14. PSRR – FIX–3.3 V,  $V_{IN} = 4.3\text{ V}$ ,  $I_{OUT} = 100\text{ mA}$

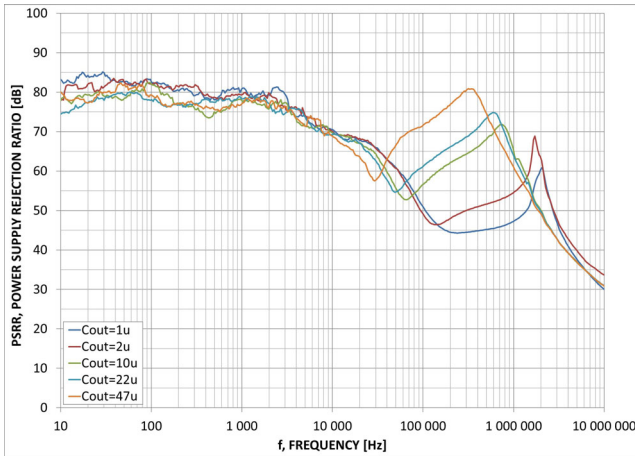


Figure 15. PSRR – FIX–3.3 V,  $V_{IN} = 8.3\text{ V}$ ,  $I_{OUT} = 100\text{ mA}$

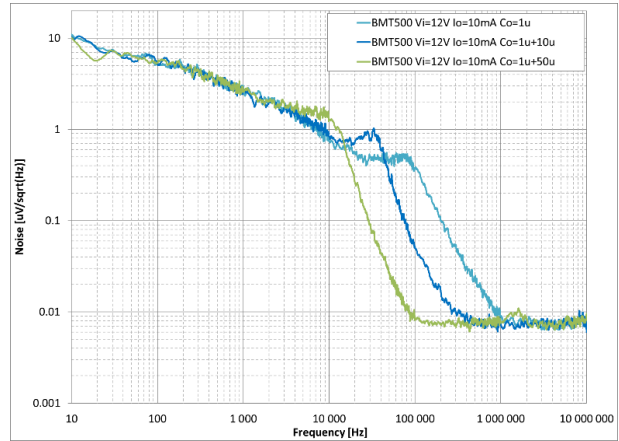


Figure 16. Noise – FIX – 5.0 V,  $I_{OUT} = 10\text{ mA}$ , Different  $C_{OUT}$

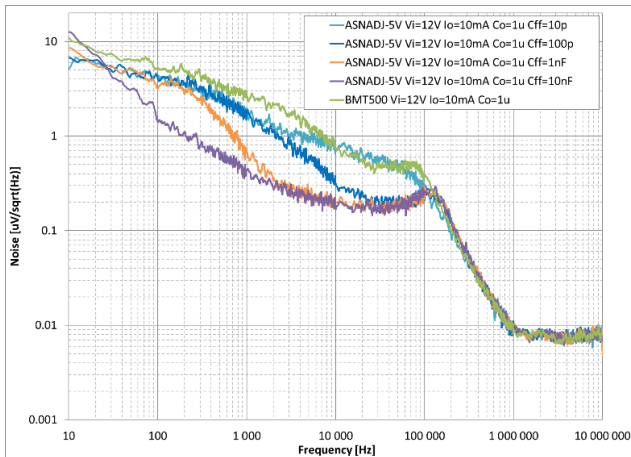


Figure 17. Noise – ADJ–set–5.0 V with Different  $C_{FF}$  and FIX – 5.0 V

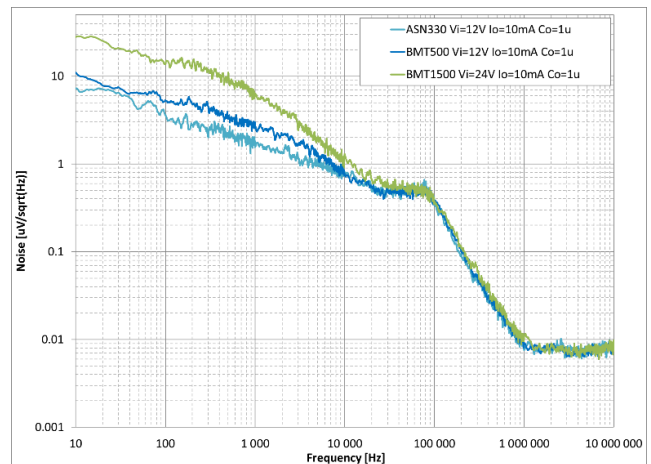


Figure 18. Noise – FIX,  $I_{OUT} = 10\text{ mA}$ ,  $C_{OUT} = 1\text{ }\mu\text{F}$ , Different  $V_{OUT}$

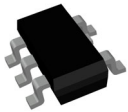


## NCV8711

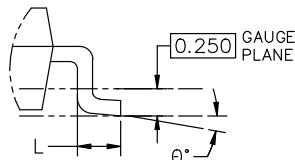
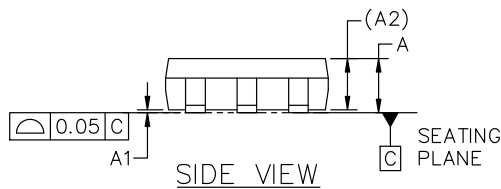
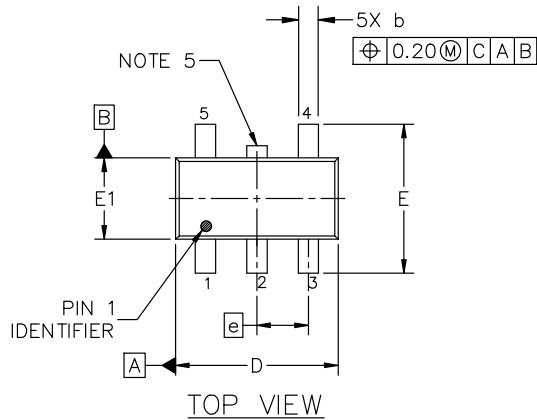
### ORDERING INFORMATION

| Part Number       | Marking | Voltage Option (V <sub>OUT-NOM</sub> ) | Version    | Package             | Shipping           |
|-------------------|---------|----------------------------------------|------------|---------------------|--------------------|
| NCV8711ASNADJT1G  | GGA     | ADJ                                    | Without PG | TSOP-5<br>(Pb-Free) | 3000 / Tape & Reel |
| NCV8711ASN300T1G  | GGC     | 3.0 V                                  |            |                     |                    |
| NCV8711ASN330T1G  | GGD     | 3.3 V                                  |            |                     |                    |
| NCV8711ASN500T1G  | GGE     | 5.0 V                                  |            |                     |                    |
| NCV8711BMTWADJTBG | GA      | ADJ                                    | With PG    | WDFNW6<br>(Pb-Free) | 3000 / Tape & Reel |
| NCV8711BMTW300TBG | GC      | 3.0 V                                  |            |                     |                    |
| NCV8711BMTW330TBG | GD      | 3.3 V                                  |            |                     |                    |
| NCV8711BMTW500TBG | GE      | 5.0 V                                  |            |                     |                    |

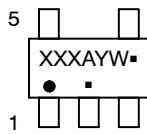
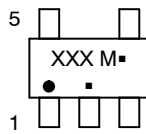
NOTE: To order other package, voltage version or PG / non PG variant, please contact your ON Semiconductor sales representative.


**TSOP-5 3.00x1.50x0.95, 0.95P**  
**CASE 483**  
**ISSUE P**

DATE 01 APR 2024



DETAIL "A"  
SCALE 2:1

**GENERIC  
MARKING DIAGRAM\***

**Analog**

**Discrete/Logic**

XXX = Specific Device Code    XXX = Specific Device Code  
A = Assembly Location    M = Date Code  
Y = Year    ■ = Pb-Free Package  
W = Work Week  
■ = Pb-Free Package

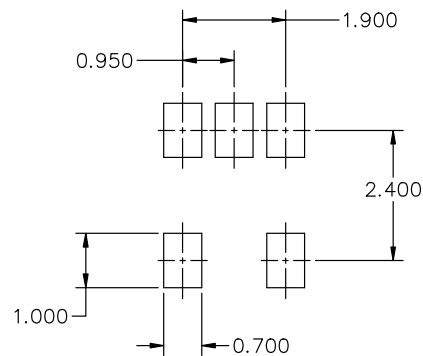
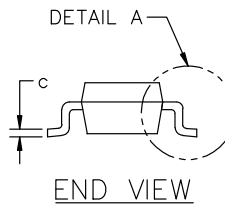
(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

**NOTES:**

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
2. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION D.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

| DIM | MILLIMETERS |       |       |
|-----|-------------|-------|-------|
|     | MIN.        | NOM.  | MAX.  |
| A   | 0.900       | 1.000 | 1.100 |
| A1  | 0.010       | 0.055 | 0.100 |
| A2  | 0.950 REF.  |       |       |
| b   | 0.250       | 0.375 | 0.500 |
| c   | 0.100       | 0.180 | 0.260 |
| D   | 2.850       | 3.000 | 3.150 |
| E   | 2.500       | 2.750 | 3.000 |
| E1  | 1.350       | 1.500 | 1.650 |
| e   | 0.950 BSC   |       |       |
| L   | 0.200       | 0.400 | 0.600 |
| θ   | 0°          | 5°    | 10°   |


**RECOMMENDED MOUNTING FOOTPRINT\***

\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERM/D.

**DOCUMENT NUMBER: 98ARB18753C**

Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

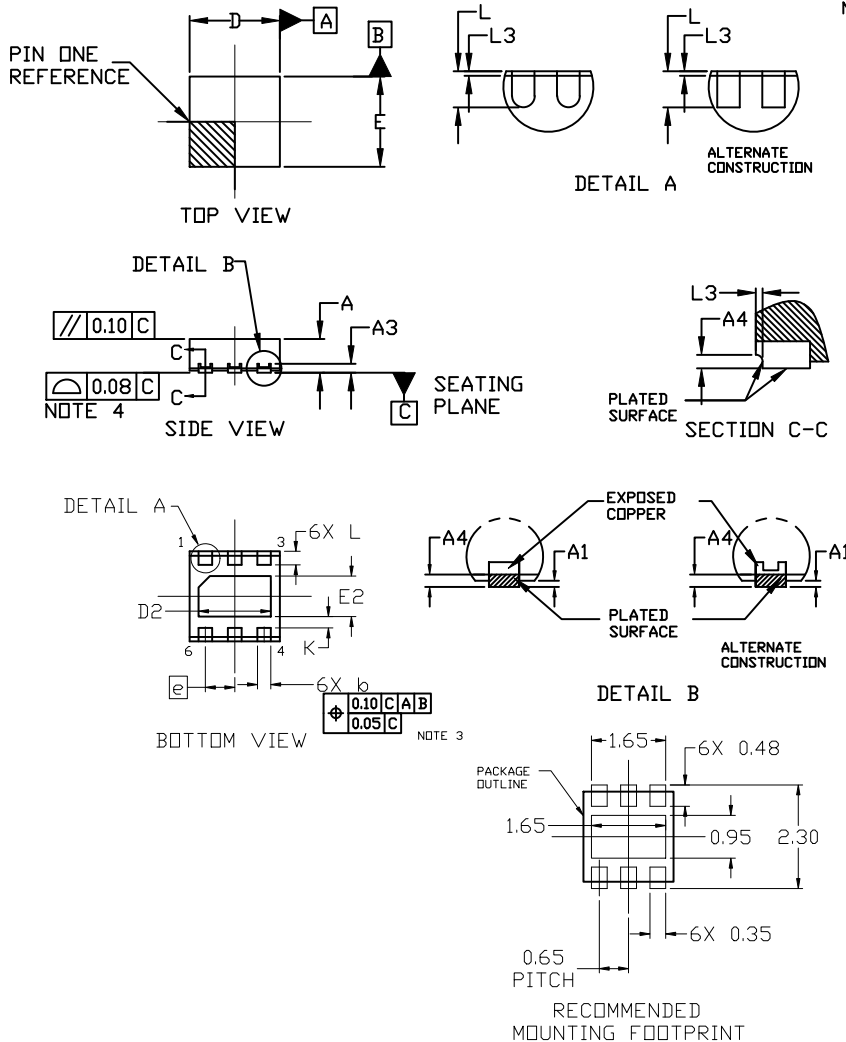
**DESCRIPTION: TSOP-5 3.00x1.50x0.95, 0.95P**
**PAGE 1 OF 1**

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.


**WDFNW6 2x2, 0.65P**  
**CASE 511DW**  
**ISSUE B**

DATE 15 JUN 2018

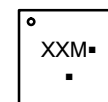
SCALE 4:1



## NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION **b** APPLIES TO PLATED TERMINALS AND IS MEASURED BETWEEN 0.15 AND 0.30MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. THIS DEVICE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

| DIM | MILLIMETERS |      |      |
|-----|-------------|------|------|
|     | MIN.        | NOM. | MAX. |
| A   | 0.70        | 0.75 | 0.80 |
| A1  | ---         | ---  | 0.05 |
| A3  | 0.20 REF    |      |      |
| A4  | 0.10        | ---  | ---  |
| b   | 0.25        | 0.30 | 0.35 |
| D   | 1.90        | 2.00 | 2.10 |
| D2  | 1.50        | 1.60 | 1.70 |
| E   | 1.90        | 2.00 | 2.10 |
| E2  | 0.80        | 0.90 | 1.00 |
| e   | 0.65 BSC    |      |      |
| K   | 0.25 REF    |      |      |
| L   | 0.25        | 0.30 | 0.35 |
| L3  | 0.05 REF    |      |      |

**GENERIC MARKING DIAGRAM\***


M = Month Code  
 ■ = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

|                         |                          |                                                                                                                                                                                  |
|-------------------------|--------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>DOCUMENT NUMBER:</b> | <b>98AON79327G</b>       | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| <b>DESCRIPTION:</b>     | <b>WDFNW6 2x2, 0.65P</b> | <b>PAGE 1 OF 1</b>                                                                                                                                                               |

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

### TECHNICAL PUBLICATIONS:

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

### ONLINE SUPPORT: [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at  
[www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)